

Small Signal Fast Switching Diode



FEATURES

- Silicon epitaxial planar diode
- Fast switching diodes
- AEC-Q101 qualified available
- Base P/N-HG3 - green, AEC-Q101 qualified
- Base P/N-G3 - green, commercial grade



RoHS
COMPLIANT
HALOGEN
FREE
GREEN
(5-2008)

MARKING (example only)



22610

Bar = cathode marking
XY = type code

MECHANICAL DATA

Case: SOD-323

Weight: approx. 4 mg

Packaging codes / options:

18/10K per 13" reel (8 mm tape), 10K/box

08/3K per 7" reel (8 mm tape), 15K/box

LINKS TO ADDITIONAL RESOURCES



3D Models

PARTS TABLE

PART	ORDERING CODE	CIRCUIT CONFIGURATION	TYPE MARKING	REMARKS
1N4148WS-G	1N4148WS-G3-08 or 1N4148WS-G3-18	Single	AH	Tape and reel
1N4148WS-HG	1N4148WS-HG3-08 or 1N4148WS-HG3-18			

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	75	V
Repetitive peak reverse voltage		V_{RRM}	100	
Average rectified current half wave rectification with resistive load ⁽¹⁾	$f \geq 50 \text{ Hz}$	$I_{F(AV)}$	150	mA
Surge forward current	$t < 1 \text{ s}$ and $T_j = 25^{\circ}\text{C}$	I_{FSM}	350	
Power dissipation ⁽¹⁾		P_{tot}	200	mW

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient temperature.

THERMAL CHARACTERISTICS ($T_{amb} = 25^{\circ}\text{C}$, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Thermal resistance junction to ambient air ⁽¹⁾		R_{thJA}	650	K/W
Junction temperature		T_j	150	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	-65 to +150	$^{\circ}\text{C}$
Operating temperature range		T_{op}	-55 to +150	$^{\circ}\text{C}$

Note

⁽¹⁾ Valid provided that electrodes are kept at ambient temperature

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 10 mA	V _F			1	V
	I _F = 100 mA	V _F			1.2	V
Leakage current	V _R = 20 V	I _R			25	nA
	V _R = 75 V	I _R			5	μA
	V _R = 100 V	I _R			100	
	V _R = 20 V, T _J = 150 °C	I _R			50	
Diode capacitance	V _F = V _R = 0 V	C _D			4	pF
Voltage rise when switching ON	Tested with 50 mA pulses, t _p = 0.1 μs, rise time < 30 ns, f _p = (5 to 100) kHz	V _{fr}			2.5	V
Reverse recovery time	I _F = 10 mA, I _R = 1 mA, V _R = 6 V, R _L = 100 Ω	t _{rr}			4	ns

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

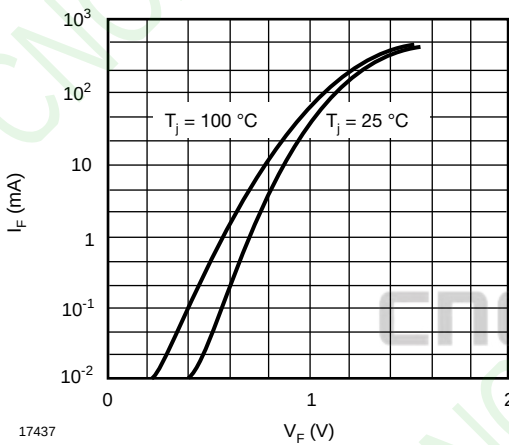


Fig. 1 - Forward Characteristics

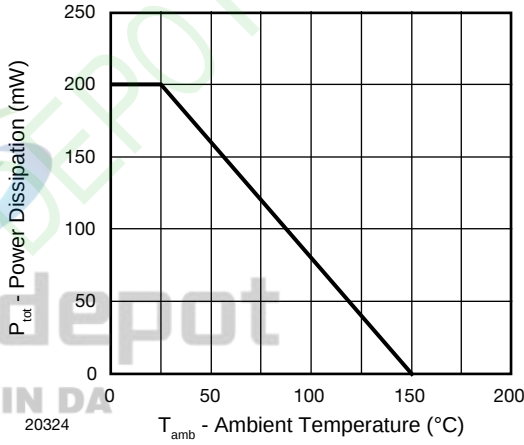


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

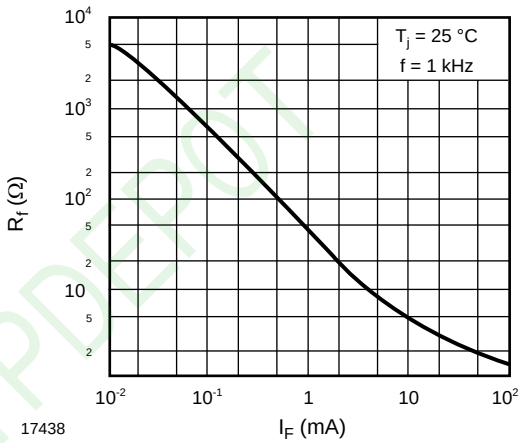


Fig. 2 - Dynamic Forward Resistance vs. Forward Current

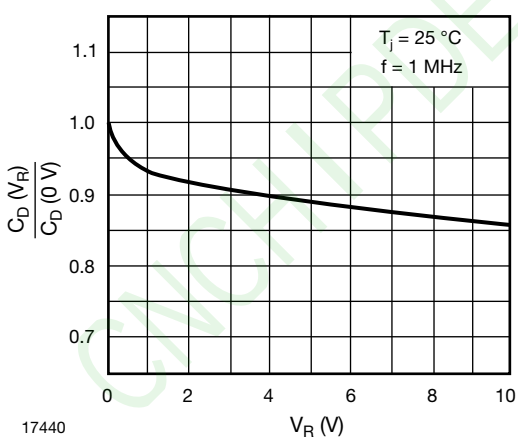


Fig. 4 - Relative Capacitance vs. Reverse Voltage

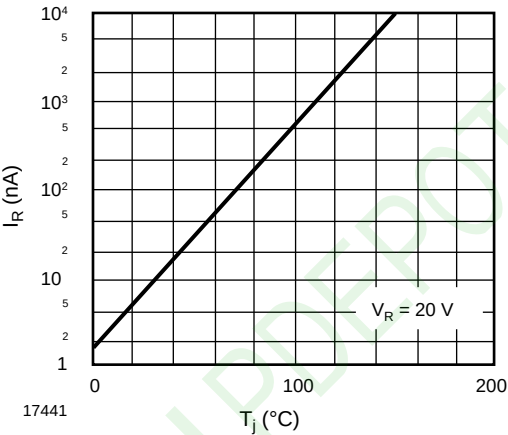


Fig. 5 - Leakage Current vs. Junction Temperature

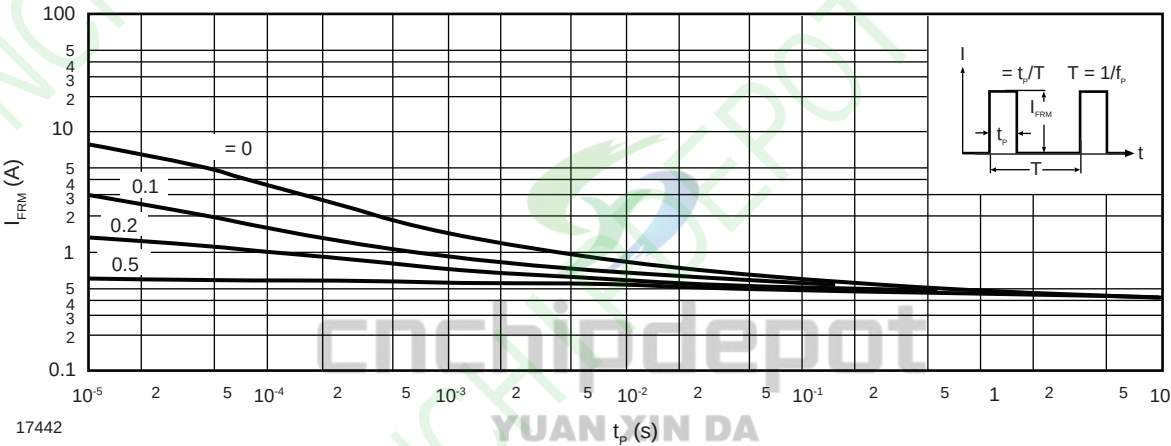
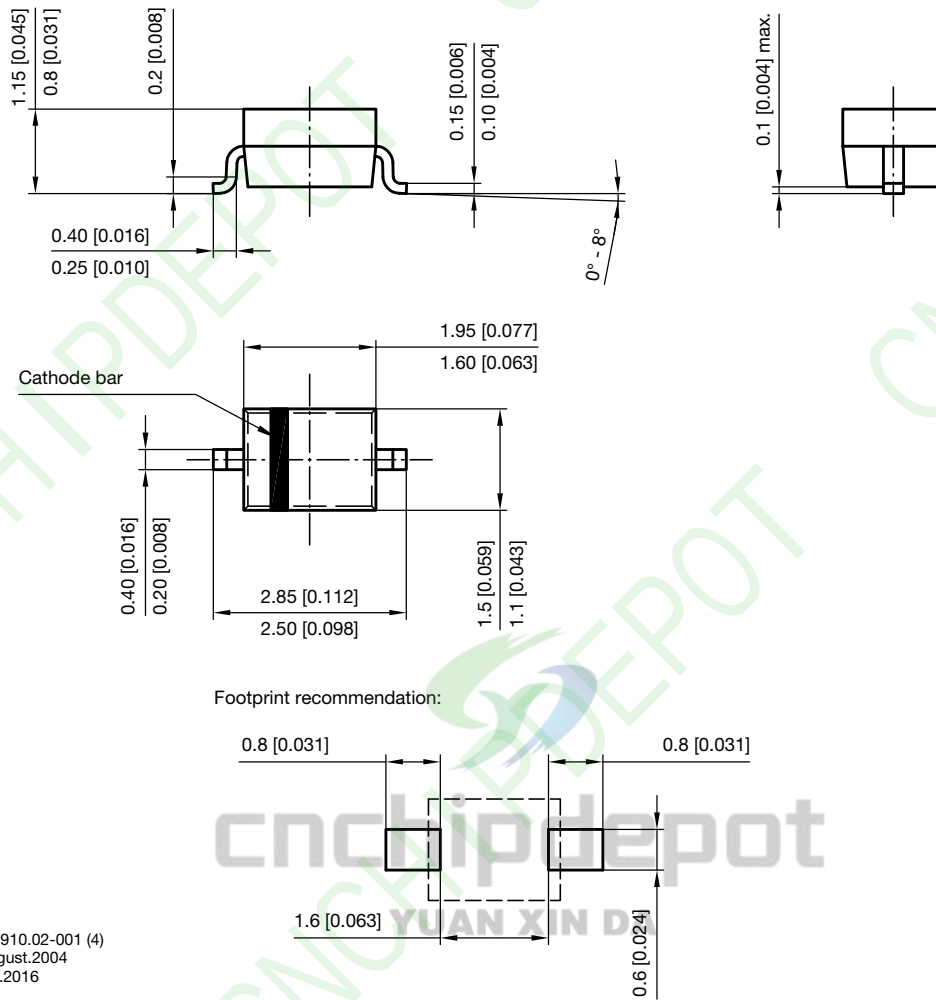


Fig. 6 - Admissible Repetitive Peak Forward Current vs. Pulse Duration

PACKAGE DIMENSIONS in millimeters (inches): **SOD-323**

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Product Portfolio

Primary Category	Secondary Category	Series	Model	Package	Link
Diode	Rectifier Diode	1N4007	1N4007	SMA(DO-214AC)	https://www.cnchipdepot.com/p/fosan-1n4007-107172.html
Diode	Rectifier Diode	1N4007	1N4007	SOD-123FL	https://www.cnchipdepot.com/p/fosan-1n4007-107173.html
Diode	Switching Diode	BAW56	BAW56	SOT-23	https://www.cnchipdepot.com/p/fosan-baw56-107174.html
Diode	Switching Diode	BAW56	BAW56W-6AF	SOT-323	https://www.cnchipdepot.com/p/fosan-baw56w-6af-107175.html

Diode	Switching Diode	1N4148	1N4148WT	SOD-323	https://www.cnchipdepot.com/p/fosan-1n4148wt-107176.html
Diode	Schottky Diode	1N5819	1N4148WS	SOD-323	https://www.cnchipdepot.com/p/fosan-1n4148ws-107177.html
Diode	Schottky Diode	SS34	SS34	SMA(DO-214AC)	https://www.cnchipdepot.com/p/fosan-ss34-107178.html
Diode	Schottky Diode	SS54	SS34B	SMA(DO-214AC)	https://www.cnchipdepot.com/p/baocheng-ss34b-12183.html
Diode	Schottky Diode	SS14	SS34C	SMA(DO-214AC)	https://www.cnchipdepot.com/p/baocheng-ss34c-12188.html
Diode Fast Recovery / High Efficiency Diode		US1M	US1M	SMA	https://www.cnchipdepot.com/p/fosan-us1m-107198.html
Diode Fast Recovery / High Efficiency Diode		US1M	US1MA-AAF	SMA	https://www.cnchipdepot.com/p/fosan-us1ma-aaf-107179.html
Diode Fast Recovery / High Efficiency Diode		US1M	US1MF	SMAF	https://www.cnchipdepot.com/p/baocheng-us1mf-17709.html
Diode	Switching Diode	BAV99	BAV99	SOT-23	https://www.cnchipdepot.com/p/agertech-bav99-18862.html
Diode	Switching Diode	BAV99	BAV99-6AF	SOT-23	https://www.cnchipdepot.com/p/fosan-ss34-107178.html
Diode	Switching Diode	BAV99	BAV99W-6AF	SOT-23	https://www.cnchipdepot.com/p/fosan-bav99w-6af-107181.html
Diode	Schottky Diode	B5819W	B5819WS	SOD-123	https://www.cnchipdepot.com/p/am-b5819ws-12167.html
Diode	Schottky Diode	B5819W	B5819W		https://www.cnchipdepot.com/p/am-b5819w-12166.html
Transistor (BJT)	NPN BJT	S8050	S8050	SOT-23	https://www.cnchipdepot.com/p/am-s8050-1108.html

Transistor (BJT)	NPN BJT	S8050	S8050-6AF	SOT-23	https://www.cnchipdepot.com/p/fosan-s8050-6af-107182.html
Transistor (BJT)	NPN BJT	SS8050	SS8050	SOT-23	https://www.cnchipdepot.com/p/alj-longjing-micro-s8050-1087.html
Transistor (BJT)	NPN BJT	SS8050	SS8050S	SOT-23	https://www.cnchipdepot.com/p/fosan-ss8050s-2326.html
Transistor (BJT)	NPN BJT	MMBT5551	MMBT5551	SOT-23	https://www.cnchipdepot.com/p/agertech-mmbt5551-1003.html
Transistor (BJT)	NPN BJT	MMBT5551	MMBT5551S	SOT-23	https://www.cnchipdepot.com/p/fosan-mmbt5551s-2327.html
Transistor (BJT)	NPN BJT	MMBT5551	MMBT5551-6AF	SOT-23	https://www.cnchipdepot.com/p/fosan-mmbt5551-6af-107183.html
Transistor	MOSFET	7002	2N7002	SOT-23	https://www.cnchipdepot.com/p/fosan-2n7002-107184.html
Transistor	MOSFET	7002	2N7002K	SOT-23	https://www.cnchipdepot.com/p/alj-longjing-micro--2n7002k-5083.html
Transistor	MOSFET	7002	2N7002K-6AF	SOT-23	https://www.cnchipdepot.com/p/fosan-2n7002k-6af-107185.html
Transistor	MOSFET	7002	2N7002-6AF	SOT-23	https://www.cnchipdepot.com/p/fosan-2n7002-6af-107186.html
Transistor	MOSFET	BSS84	BSS84	SOT-23	https://www.cnchipdepot.com/p/fosan-bss84-107187.html
Transistor	MOSFET	BSS84	BSS84-6AF	SOT-363	https://www.cnchipdepot.com/p/fosan-bss84-6af-107188.html
Transistor (BJT)	NPN BJT	BC847	BC847A	SOT-23	https://www.cnchipdepot.com/p/alj-longjing-micro--bc847a-1052.html
Transistor (BJT)	NPN BJT	BC847	BC847B	SOT-23	https://www.cnchipdepot.com/p/alj-longjing-micro--bc847b-1056.html

Transistor (BJT)	NPN BJT	BC847	BC847C	SOT-23	https://www.cnchipdepot.com/p/alj-longjing-micro--bc847c-1055.html
Power IC	LDO	1117	LD1117-3.3	SOT223	https://www.cnchipdepot.com/p/hxy-mosfet-huaxuan-yang-electronics--ld1117-3-3-25490.html
Power IC	LDO	1117	LD1117-1.8	SOT223	https://www.cnchipdepot.com/p/hxy-mosfet-huaxuan-yang-electronics--ld1117-1-8-25429.html
Power IC	LDO	1117	LD1117-5.0	SOT223	https://www.cnchipdepot.com/p/hxy-mosfet-huaxuan-yang-electronics--ld1117-5-0-25444.html
Power IC	LDO	1117	LD1117-ADJ	SOT223	https://www.cnchipdepot.com/p/hxy-mosfet-huaxuan-yang-electronics--ld1117-adj-25427.html


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